

Surface Mount Schottky Barrier Diode

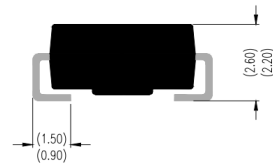
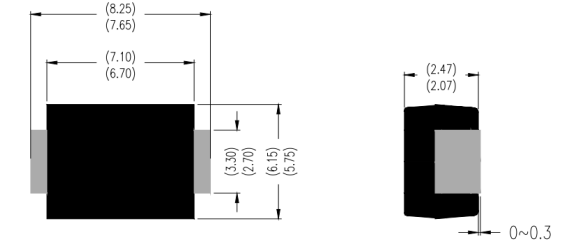
Features

- Low profile package
- Ideal for automated placement
- Guardring for overvoltage protection
- Low power losses, high efficiency
- High forward surge capability
- Compliant with RoHS standards, halogen-free

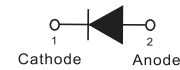
Mechanical Data

- **Package:** SMC/DO-214AB
- **Terminals:** Tin plated leads, solderable per
- **Polarity:** Color band denotes the cathode end

SMC/DO-214AB



Unit : inch(mm)



Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Unit	SS52C	SS53C	SS54C	SS55C	SS56C	SS58C	SS510C	SS515C	SS520C
Repetitive peak reverse voltage	V_{RRM}	V	20	30	40	50	60	80	100	150	200
Average rectified output current @60Hz sine wave, resistance load, TL (FIG.1)	I_O	A	5.0								
Surge(non-repetitive)forward current @60Hz half-sine wave, 1 cycle, $T_a=25^\circ\text{C}$	I_{FSM}	A	100								
Storage temperature	T_{stg}	$^\circ\text{C}$	-55 ~+150								
Junction temperature	T_j	$^\circ\text{C}$	-55 ~+150					-55 ~+175			

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Unit	Test Conditions	SS52C	SS53C	SS54C	SS55C	SS56C	SS58C	SS510C	SS515C	SS520C
Maximum instantaneous forward voltage drop per diode	V _F	V	I _{FM} =5.0A	0.55			0.70		0.85		0.95	
Maximum DC reverse current at rated DC blocking voltage per diode @ V _{RM} =V _{RRM}	I _{RRM}	mA	Ta=25°C	0.2					0.1			
			Ta=100°C	20					5			

Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Unit	SS52C	SS53C	SS54C	SS55C	SS56C	SS58C	SS510C	SS515C	SS520C
Thermal Resistance	Junction to ambient	$R_{\theta J-A}$	$^\circ\text{C/W}$	47 ⁽¹⁾								
	Junction to lead	$R_{\theta J-L}$		13 ⁽¹⁾								

Note(1)

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.6" x 0.6" (16 mm x 16 mm) copper pad areas

Characteristics (Typical)

FIG.1: I_o - T_a Curve

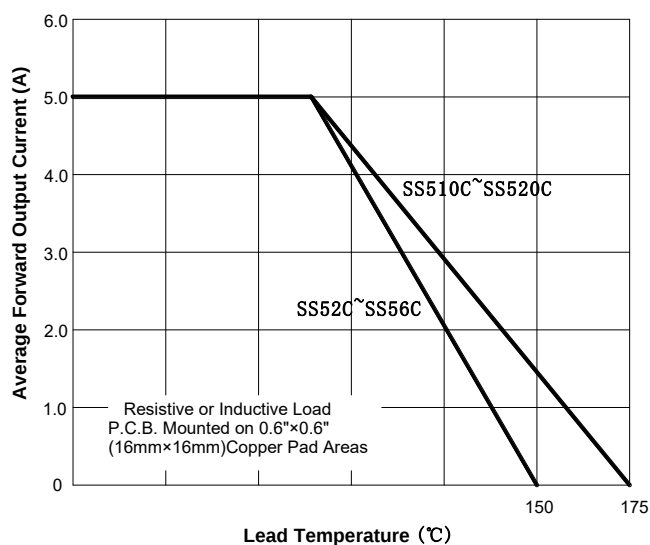


FIG.2: Forward Surge Current Capability

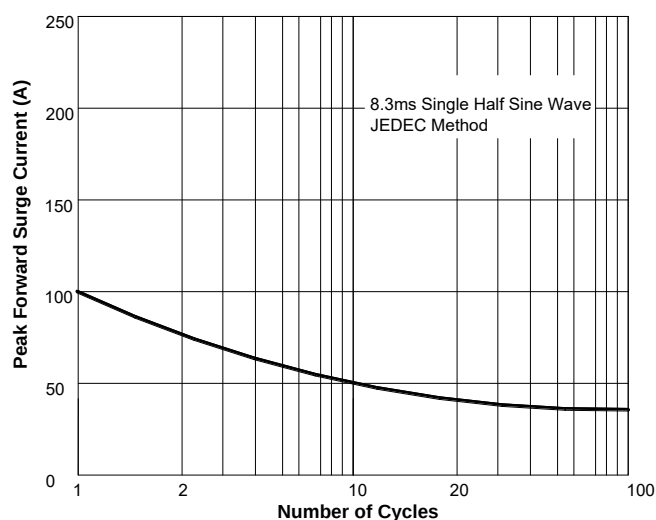


FIG.3: Forward Voltage

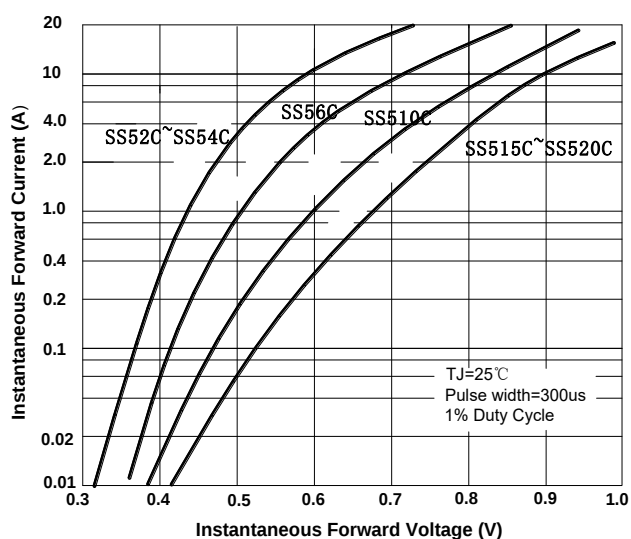


FIG.4: Typical Reverse Characteristics

